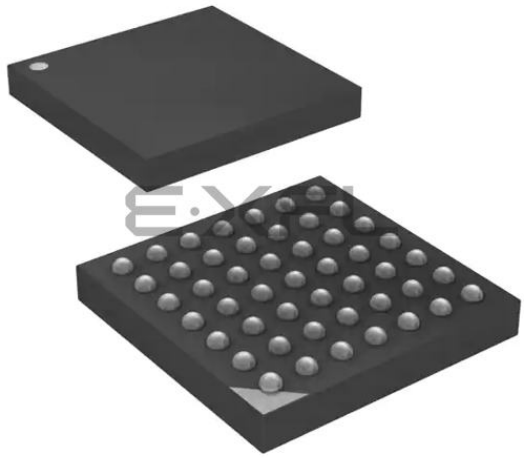

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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	AVR
Core Size	8/16-Bit
Speed	32MHz
Connectivity	I²C, IrDA, SPI, UART/USART, USB
Peripherals	Brown-out Detect/Reset, DMA, POR, PWM, WDT
Number of I/O	34
Program Memory Size	64KB (32K x 16)
Program Memory Type	FLASH
EEPROM Size	2K x 8
RAM Size	4K x 8
Voltage - Supply (Vcc/Vdd)	1.6V ~ 3.6V
Data Converters	A/D 12x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	49-VFBGA
Supplier Device Package	49-VFBGA (5x5)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/atxmega64a4u-cur

8. DMAC – Direct Memory Access Controller

8.1 Features

- Allows high speed data transfers with minimal CPU intervention
  - from data memory to data memory
  - from data memory to peripheral
  - from peripheral to data memory
  - from peripheral to peripheral
- Four DMA channels with separate
  - transfer triggers
  - interrupt vectors
  - addressing modes
- Programmable channel priority
- From 1 byte to 16MB of data in a single transaction
  - Up to 64KB block transfers with repeat
  - 1, 2, 4, or 8 byte burst transfers
- Multiple addressing modes
  - Static
  - Incremental
  - Decremental
- Optional reload of source and destination addresses at the end of each
  - Burst
  - Block
  - Transaction
- Optional interrupt on end of transaction
- Optional connection to CRC generator for CRC on DMA data

8.2 Overview

The four-channel direct memory access (DMA) controller can transfer data between memories and peripherals, and thus offload these tasks from the CPU. It enables high data transfer rates with minimum CPU intervention, and frees up CPU time. The four DMA channels enable up to four independent and parallel transfers.

The DMA controller can move data between SRAM and peripherals, between SRAM locations and directly between peripheral registers. With access to all peripherals, the DMA controller can handle automatic transfer of data to/from communication modules. The DMA controller can also read from memory mapped EEPROM.

Data transfers are done in continuous bursts of 1, 2, 4, or 8 bytes. They build block transfers of configurable size from 1 byte to 64KB. A repeat counter can be used to repeat each block transfer for single transactions up to 16MB. Source and destination addressing can be static, incremental or decremental. Automatic reload of source and/or destination addresses can be done after each burst or block transfer, or when a transaction is complete. Application software, peripherals, and events can trigger DMA transfers.

The four DMA channels have individual configuration and control settings. This include source, destination, transfer triggers, and transaction sizes. They have individual interrupt settings. Interrupt requests can be generated when a transaction is complete or when the DMA controller detects an error on a DMA channel.

To allow for continuous transfers, two channels can be interlinked so that the second takes over the transfer when the first is finished, and vice versa.

11.3.3 Power-save Mode

Power-save mode is identical to power down, with one exception. If the real-time counter (RTC) is enabled, it will keep running during sleep, and the device can also wake up from either an RTC overflow or compare match interrupt.

11.3.4 Standby Mode

Standby mode is identical to power down, with the exception that the enabled system clock sources are kept running while the CPU, peripheral, and RTC clocks are stopped. This reduces the wake-up time.

11.3.5 Extended Standby Mode

Extended standby mode is identical to power-save mode, with the exception that the enabled system clock sources are kept running while the CPU and peripheral clocks are stopped. This reduces the wake-up time.

28. ADC – 12-bit Analog to Digital Converter

28.1 Features

- One Analog to Digital Converter (ADC)
- 12-bit resolution
- Up to two million samples per second
  - Two inputs can be sampled simultaneously using ADC and 1x gain stage
  - Four inputs can be sampled within 1.5µs
  - Down to 2.5µs conversion time with 8-bit resolution
  - Down to 3.5µs conversion time with 12-bit resolution
- Differential and single-ended input
  - Up to 12 single-ended inputs
  - 12x4 differential inputs without gain
  - 8x4 differential inputs with gain
- Built-in differential gain stage
  - 1/2x, 1x, 2x, 4x, 8x, 16x, 32x, and 64x gain options
- Single, continuous and scan conversion options
- Four internal inputs
  - Internal temperature sensor
  - DAC output
  - AV_{CC} voltage divided by 10
  - 1.1V bandgap voltage
- Four conversion channels with individual input control and result registers
  - Enable four parallel configurations and results
- Internal and external reference options
- Compare function for accurate monitoring of user defined thresholds
- Optional event triggered conversion for accurate timing
- Optional DMA transfer of conversion results
- Optional interrupt/event on compare result

28.2 Overview

The ADC converts analog signals to digital values. The ADC has 12-bit resolution and is capable of converting up to two million samples per second (msps). The input selection is flexible, and both single-ended and differential measurements can be done. For differential measurements, an optional gain stage is available to increase the dynamic range. In addition, several internal signal inputs are available. The ADC can provide both signed and unsigned results.

This is a pipelined ADC that consists of several consecutive stages. The pipelined design allows a high sample rate at a low system clock frequency. It also means that a new input can be sampled and a new ADC conversion started while other ADC conversions are still ongoing. This removes dependencies between sample rate and propagation delay.

The ADC has four conversion channels (0-3) with individual input selection, result registers, and conversion start control. The ADC can then keep and use four parallel configurations and results, and this will ease use for applications with high data throughput or for multiple modules using the ADC independently. It is possible to use DMA to move ADC results directly to memory or peripherals when conversions are done.

Both internal and external reference voltages can be used. An integrated temperature sensor is available for use with the ADC. The output from the DAC, $AV_{CC}/10$ and the bandgap voltage can also be measured by the ADC.

The ADC has a compare function for accurate monitoring of user defined thresholds with minimum software intervention required.

32.1.1 Operation/Power Supply

V_{CC}	Digital supply voltage
AV_{CC}	Analog supply voltage
GND	Ground

32.1.2 Port Interrupt functions

SYNC	Port pin with full synchronous and limited asynchronous interrupt function
ASYNC	Port pin with full synchronous and full asynchronous interrupt function

32.1.3 Analog functions

ACn	Analog Comparator input pin n
ACnOUT	Analog Comparator n Output
ADCn	Analog to Digital Converter input pin n
DACn	Digital to Analog Converter output pin n
A_{REF}	Analog Reference input pin

32.1.4 Timer/Counter and AWEX functions

OCnxLS	Output Compare Channel x Low Side for Timer/Counter n
OCnxHS	Output Compare Channel x High Side for Timer/Counter n

36.1.3 Current consumption

Table 36-4. Current consumption for Active mode and sleep modes.

Symbol	Parameter	Condition		Min.	Typ.	Max.	Units
I_{CC}	Active power consumption (1)	32kHz, Ext. Clk	V_{CC} = 1.8V		40		µA
			V_{CC} = 3.0V		80		
		1MHz, Ext. Clk	V_{CC} = 1.8V		230		
			V_{CC} = 3.0V		480		
		2MHz, Ext. Clk	V_{CC} = 1.8V		430	600	
			V_{CC} = 3.0V		0.9	1.4	mA
		32MHz, Ext. Clk			9.6	12	
	Idle power consumption (1)	32kHz, Ext. Clk	V_{CC} = 1.8V		2.4		µA
			V_{CC} = 3.0V		3.9		
		1MHz, Ext. Clk	V_{CC} = 1.8V		62		
			V_{CC} = 3.0V		118		
		2MHz, Ext. Clk	V_{CC} = 1.8V		125	225	
			V_{CC} = 3.0V		240	350	
		32MHz, Ext. Clk			3.8	5.5	mA
	Power-down power consumption	T = 25°C	V_{CC} = 3.0V		0.1	1.0	µA
		T = 85°C			1.2	4.5	
		T = 105°C			3.5	6.0	
		WDT and Sampled BOD enabled, T = 25°C	V_{CC} = 3.0V		1.3	3.0	
		WDT and Sampled BOD enabled, T = 85°C			2.4	6.0	
		WDT and Sampled BOD enabled, T = 105°C			4.5	8.0	
	Power-save power consumption (2)	RTC from ULP clock, WDT and sampled BOD enabled, T = 25°C	V_{CC} = 1.8V		1.2		µA
			V_{CC} = 3.0V		1.3		
		RTC from 1.024kHz low power 32.768kHz TOSC, T = 25°C	V_{CC} = 1.8V		0.6	2.0	
			V_{CC} = 3.0V		0.7	2.0	
		RTC from low power 32.768kHz TOSC, T = 25°C	V_{CC} = 1.8V		0.8	3.0	
			V_{CC} = 3.0V		1.0	3.0	
	Reset power consumption	Current through $\overline{\text{RESET}}$ pin substracted	V_{CC} = 3.0V		320		µA

Notes:
1. All Power Reduction Registers set.
2. Maximum limits are based on characterization, and not tested in production.

36.3.3 Current consumption

Table 36-68. Current consumption for Active mode and sleep modes.

Symbol	Parameter	Condition		Min.	Typ.	Max.	Units
I_{CC}	Active power consumption (1)	32kHz, Ext. Clk	V_{CC} = 1.8V		52		µA
			V_{CC} = 3.0V		132		
		1MHz, Ext. Clk	V_{CC} = 1.8V		223		
			V_{CC} = 3.0V		476		
		2MHz, Ext. Clk	V_{CC} = 1.8V		400	600	
			V_{CC} = 3.0V		0.8	1.4	mA
		32MHz, Ext. Clk			8.2	12	
	Idle power consumption (1)	32kHz, Ext. Clk	V_{CC} = 1.8V		2.4		µA
			V_{CC} = 3.0V		3.5		
		1MHz, Ext. Clk	V_{CC} = 1.8V		57		
			V_{CC} = 3.0V		110		
		2MHz, Ext. Clk	V_{CC} = 1.8V		115	225	
			V_{CC} = 3.0V		216	350	
		32MHz, Ext. Clk			3.5	5.5	mA
	Power-down power consumption	T = 25°C	V_{CC} = 3.0V		0.1	1.0	µA
		T = 85°C			1.2	4.5	
		T = 105°C			2.4	6.0	
		WDT and Sampled BOD enabled, T = 25°C	V_{CC} = 3.0V		1.4	3.0	
		WDT and Sampled BOD enabled, T = 85°C			2.4	6.0	
		WDT and Sampled BOD enabled, T = 105°C			3.5	8.0	
	Power-save power consumption (2)	RTC from ULP clock, WDT and sampled BOD enabled, T = 25°C	V_{CC} = 1.8V		1.2		µA
			V_{CC} = 3.0V		1.5		
		RTC from 1.024kHz low power 32.768kHz TOSC, T = 25°C	V_{CC} = 1.8V		0.6	2.0	
			V_{CC} = 3.0V		0.7	2.0	
		RTC from low power 32.768kHz TOSC, T = 25°C	V_{CC} = 1.8V		0.8	3.0	
			V_{CC} = 3.0V		1.0	3.0	
	Reset power consumption	Current through $\overline{\text{RESET}}$ pin substracted	V_{CC} = 3.0V		140		

Notes:
1. All Power Reduction Registers set.
2. Maximum limits are based on characterization, and not tested in production.

36.3.6 ADC characteristics

Table 36-72. Power supply, reference and input range.

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
AV_{CC}	Analog supply voltage		V_{CC}- 0.3		V_{CC}+ 0.3	V
V_{REF}	Reference voltage		1.0		AV_{CC}- 0.6	V
R_{in}	Input resistance	Switched		4.0		kΩ
C_{sample}	Input capacitance	Switched		4.4		pF
R_{AREF}	Reference input resistance	(leakage only)		>10		MΩ
C_{AREF}	Reference input capacitance	Static load		7.0		pF
V_{IN}	Input range		-0.1		AV_{CC}+0.1	V
	Conversion range	Differential mode, Vinp - Vinn	$-V_{REF}$		V_{REF}	V
	Conversion range	Single ended unsigned mode, Vinp	-ΔV		V_{REF}-ΔV	V
ΔV	Fixed offset voltage			190		lsb

Table 36-73. Clock and timing.

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
Clk_{ADC}	ADC clock frequency	Maximum is 1/4 of peripheral clock frequency	100		2000	kHz
		Measuring internal signals	100		125	
f_{ADC}	Sample rate	Current limitation (CURRLIMIT) off	100		2000	ksps
		CURRLIMIT = LOW	100		1500	
		CURRLIMIT = MEDIUM	100		1000	
		CURRLIMIT = HIGH	100		500	
	Sampling time	1/2 Clk_{ADC} cycle	0.25		5	µs
	Conversion time (latency)	(RES+2)/2+(GAIN !=0) RES (Resolution) = 8 or 12	5		8	Clk_{ADC} cycles
	Start-up time	ADC clock cycles		12	24	Clk_{ADC} cycles
	ADC settling time	After changing reference or input mode		7	7	Clk_{ADC} cycles
		After ADC flush		1	1	

36.3.10 Brownout Detection Characteristics

Table 36-81. Brownout detection characteristics.

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
V_{BOT}	BOD level 0 falling V_{CC}		1.50	1.62	1.72	V
	BOD level 1 falling V_{CC}			1.8		
	BOD level 2 falling V_{CC}			2.0		
	BOD level 3 falling V_{CC}			2.2		
	BOD level 4 falling V_{CC}			2.4		
	BOD level 5 falling V_{CC}			2.6		
	BOD level 6 falling V_{CC}			2.8		
	BOD level 7 falling V_{CC}			3.0		
t_{BOD}	Detection time	Continuous mode		0.4		µs
		Sampled mode		1000		
V_{HYST}	Hysteresis			1.2		%

36.3.11 External Reset Characteristics

Table 36-82. External reset characteristics.

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
t_{EXT}	Minimum reset pulse width		1000	95		ns
V_{RST}	Reset threshold voltage (V_{IH})	V_{CC} = 2.7 - 3.6V		0.60×V_{CC}		V
		V_{CC} = 1.6 - 2.7V		0.60×V_{CC}		
	Reset threshold voltage (V_{IL})	V_{CC} = 2.7 - 3.6V		0.50×V_{CC}		
		V_{CC} = 1.6 - 2.7V		0.40×V_{CC}		
R_{RST}	Reset pin Pull-up Resistor			25		kΩ

36.3.12 Power-on Reset Characteristics

Table 36-83. Power-on reset characteristics.

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
V_{POT-} (1)	POR threshold voltage falling V_{CC}	V_{CC} falls faster than 1V/ms	0.4	1.0		V
		V_{CC} falls at 1V/ms or slower	0.8	1.0		
V_{POT+}	POR threshold voltage rising V_{CC}			1.3	1.59	

Note: 1. V_{POT-} values are only valid when BOD is disabled. When BOD is enabled V_{POT-} = V_{POT+}.

36.4.6 ADC characteristics

Table 36-104.Power supply, reference and input range.

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
AV_{CC}	Analog supply voltage		V_{CC}- 0.3		V_{CC}+ 0.3	V
V_{REF}	Reference voltage		1		AV_{CC}- 0.6	V
R_{in}	Input resistance	Switched		4.0		kΩ
C_{sample}	Input capacitance	Switched		4.4		pF
R_{AREF}	Reference input resistance	(leakage only)		>10		MΩ
C_{AREF}	Reference input capacitance	Static load		7		pF
V_{IN}	Input range		-0.1		AV_{CC}+0.1	V
	Conversion range	Differential mode, Vinp - Vinn	$-V_{REF}$		V_{REF}	V
	Conversion range	Single ended unsigned mode, Vinp	-ΔV		V_{REF}-ΔV	V
ΔV	Fixed offset voltage			190		lsb

Table 36-105.Clock and timing.

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
Clk_{ADC}	ADC Clock frequency	Maximum is 1/4 of Peripheral clock frequency	100		2000	kHz
		Measuring internal signals	100		125	
f_{ADC}	Sample rate	Current limitation (CURRLIMIT) off	100		2000	ksps
		CURRLIMIT = LOW	100		1500	
		CURRLIMIT = MEDIUM	100		1000	
		CURRLIMIT = HIGH	100		500	
	Sampling time	1/2 Clk_{ADC} cycle	0.25		5	µs
	Conversion time (latency)	(RES+2)/2+(GAIN !=0) RES (Resolution) = 8 or 12	5		8	Clk_{ADC} cycles
	Start-up time	ADC clock cycles		12	24	Clk_{ADC} cycles
	ADC settling time	After changing reference or input mode		7	7	Clk_{ADC} cycles
		After ADC flush		1	1	

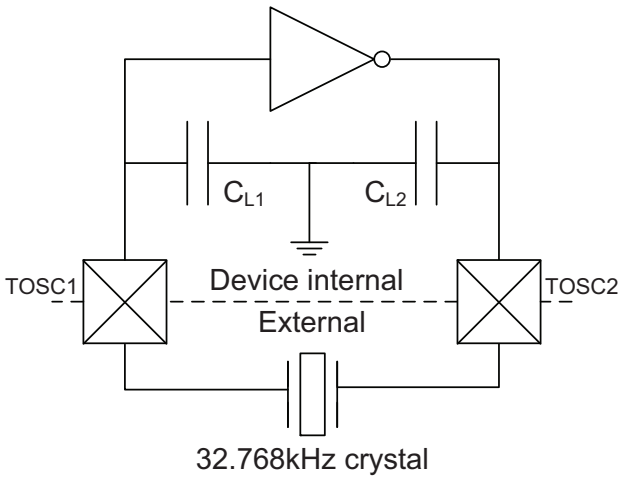
36.4.14.8 External 32.768kHz crystal oscillator and TOSC characteristics

Table 36-126. External 32.768kHz crystal oscillator and TOSC characteristics.

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
ESR/R1	Recommended crystal equivalent series resistance (ESR)	Crystal load capacitance 6.5pF			60	kΩ
		Crystal load capacitance 9.0pF			35	
C_{TOSC1}	Parasitic capacitance TOSC1 pin			5.4		pF
		Alternate TOSC location		4.0		
C_{TOSC2}	Parasitic capacitance TOSC2 pin			7.1		pF
		Alternate TOSC location		4.0		
	Recommended safety factor	capacitance load matched to crystal specification	3			

Note: 1. See Figure 36-25 for definition.

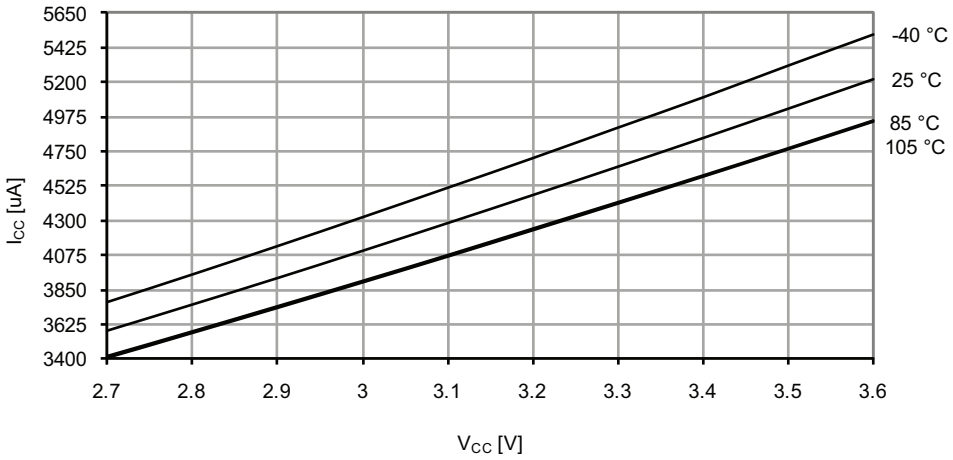
Figure 36-25. TOSC input capacitance.



The parasitic capacitance between the TOSC pins is C_{L1} + C_{L2} in series as seen from the crystal when oscillating without external capacitors.

Figure 37-7. Active mode supply current vs. V_{CC}.

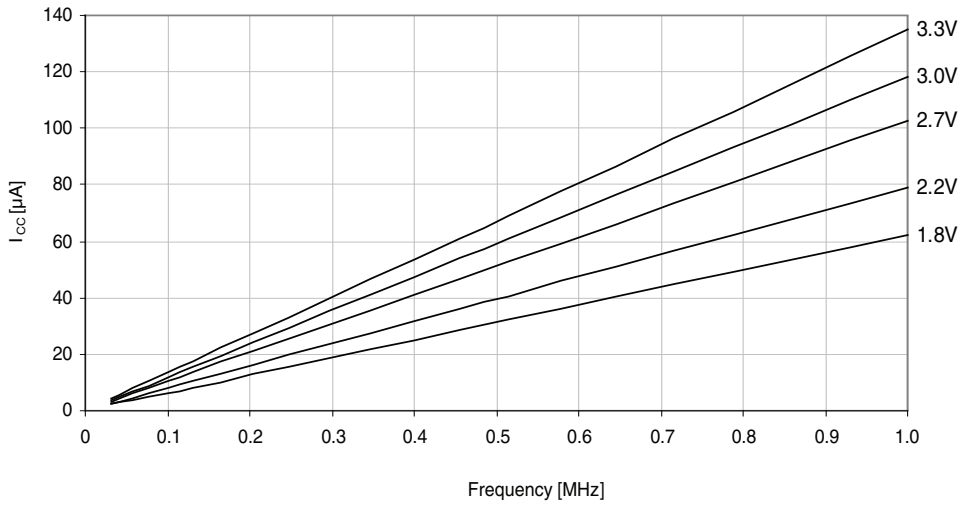
f_{SYS} = 32MHz internal oscillator.



37.1.1.2 Idle mode supply current

Figure 37-8. Idle mode supply current vs. frequency.

f_{SYS} = 0 - 1MHz external clock, T = 25°C.



37.1.1.5 Standby mode supply current

Figure 37-19. Standby supply current vs. V_{CC}.

Standby, f_{SYS} = 1MHz.

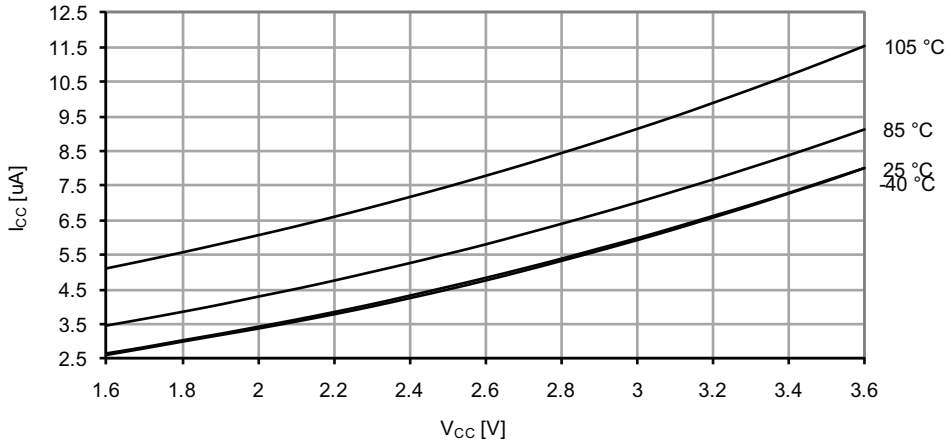


Figure 37-20. Standby supply current vs. V_{CC}.

25°C, running from different crystal oscillators.

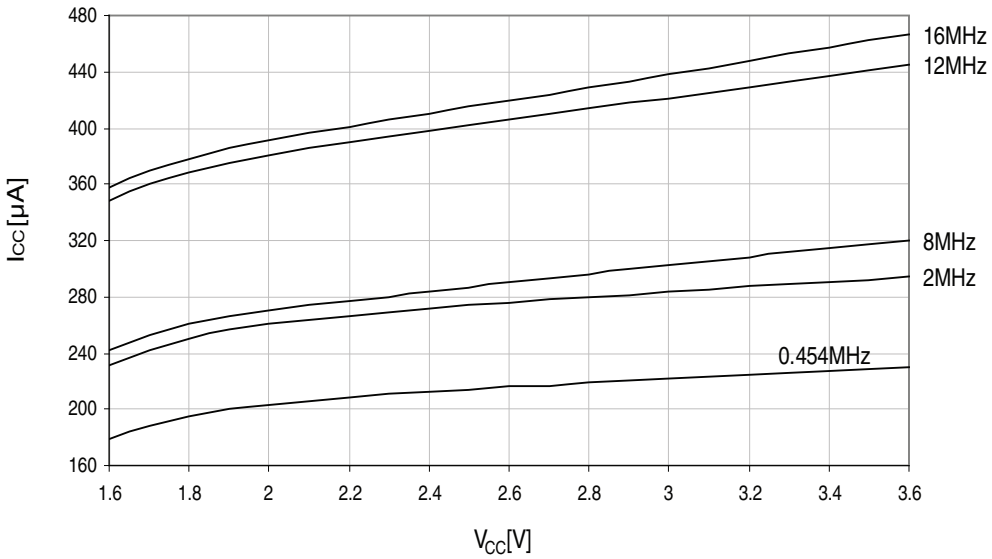


Figure 37-29. I/O pin output voltage vs. sink current.

V_{CC} = 3.0V.

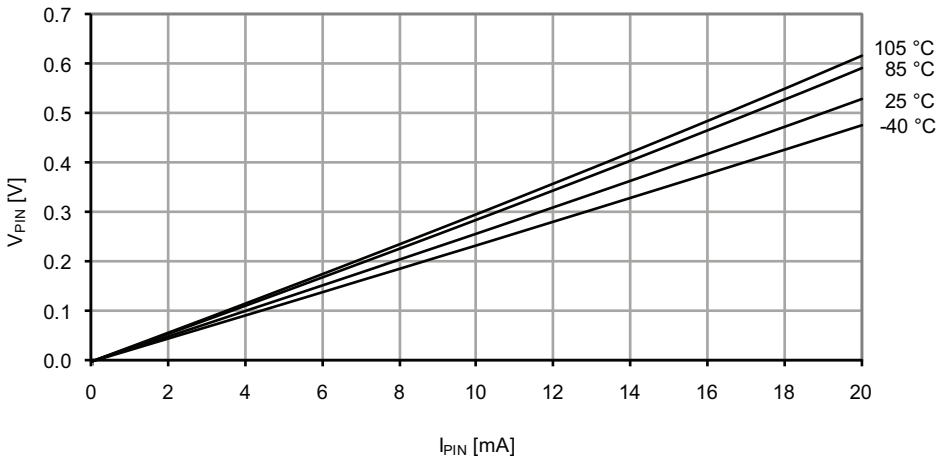


Figure 37-30. I/O pin output voltage vs. sink current.

V_{CC} = 3.3V.

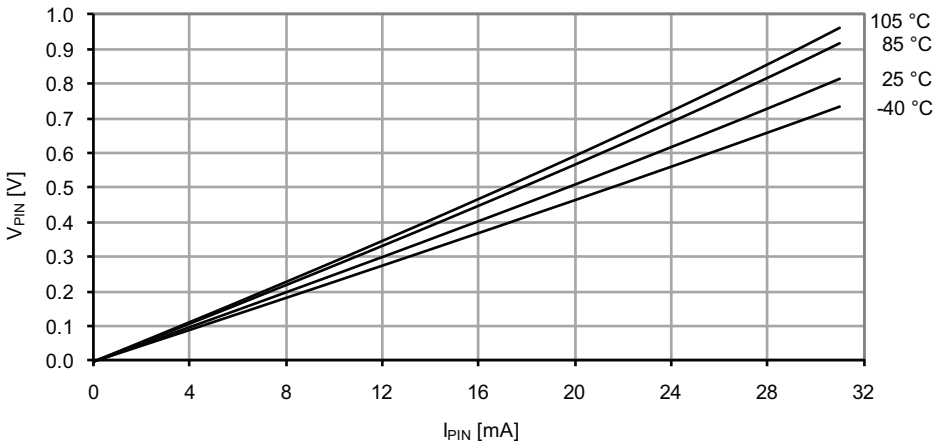


Figure 37-31. I/O pin output voltage vs. sink current.

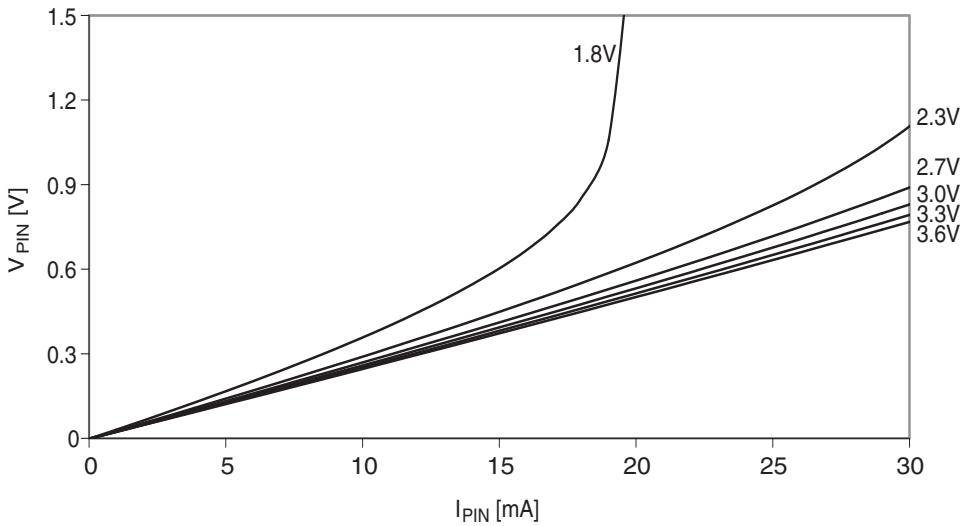


Figure 37-50. DNL error vs. V_{REF}.

V_{CC} = 3.6V.

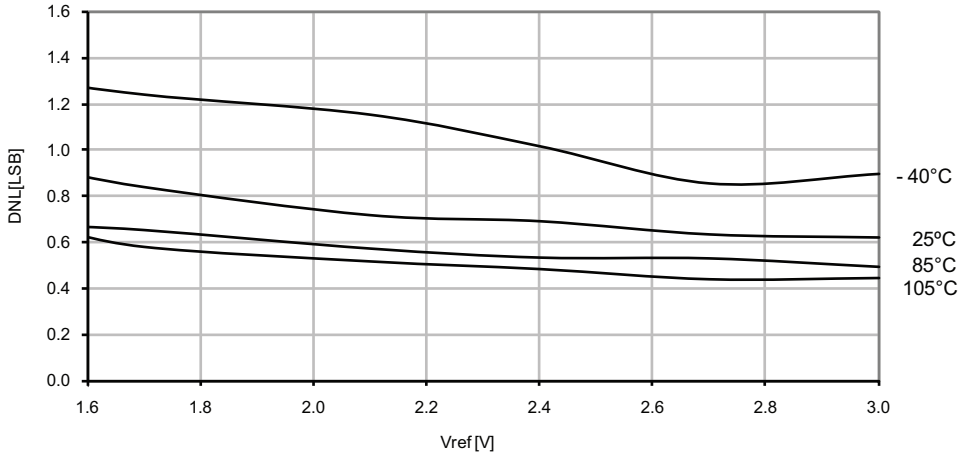


Figure 37-51. DAC noise vs. temperature.

V_{CC} = 3.0V, V_{REF} = 2.4V .

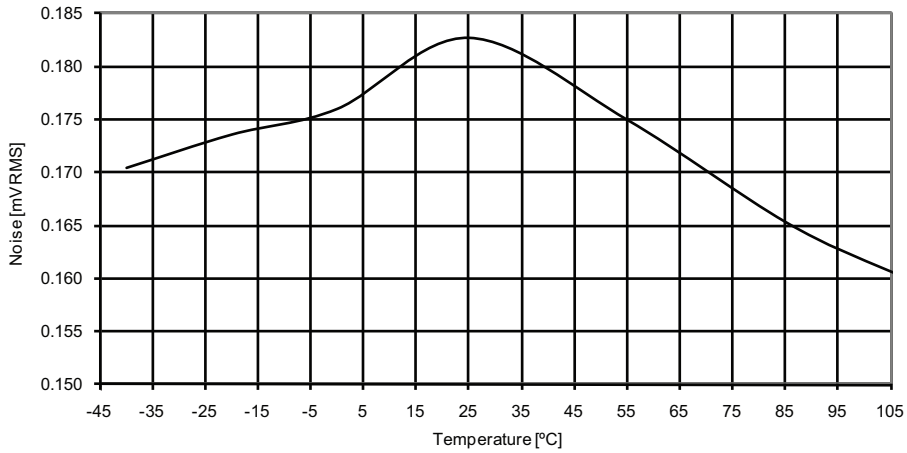


Figure 37-66. Reset pin input threshold voltage vs. V_{CC}.

V_{IH} - Reset pin read as "1".

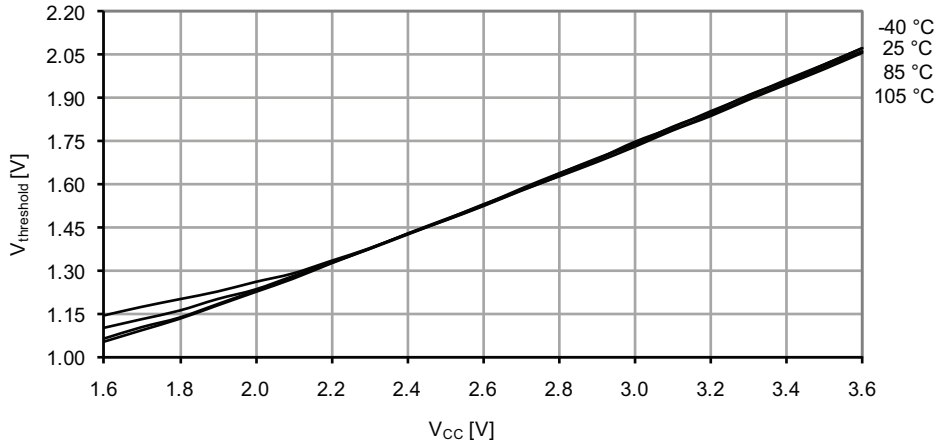
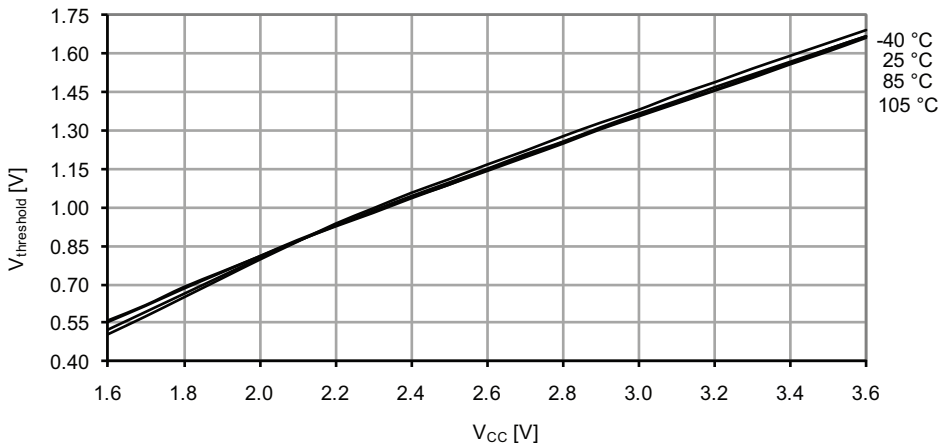


Figure 37-67. Reset pin input threshold voltage vs. V_{CC}.

V_{IL} - Reset pin read as "0".



37.1.10.5 32MHz internal oscillator calibrated to 48MHz

Figure 37-80. 48MHz internal oscillator frequency vs. temperature.

DFLL disabled.

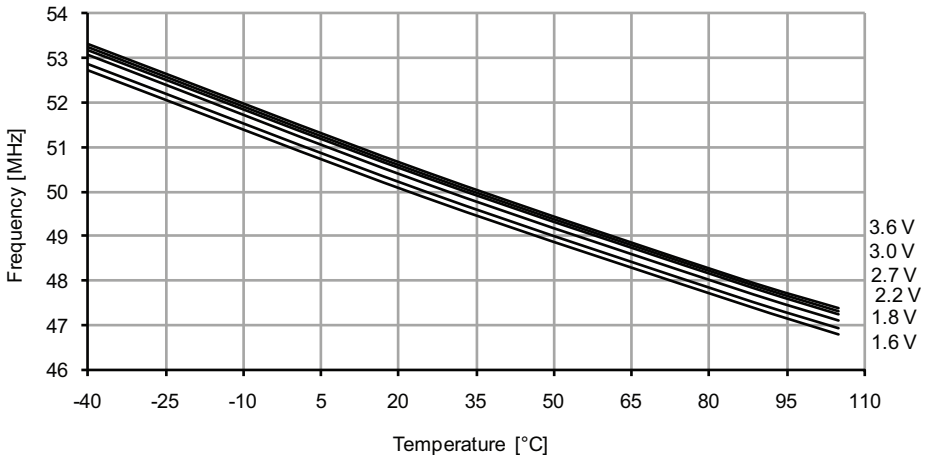


Figure 37-81. 48MHz internal oscillator frequency vs. temperature.

DFLL enabled, from the 32.768kHz internal oscillator.

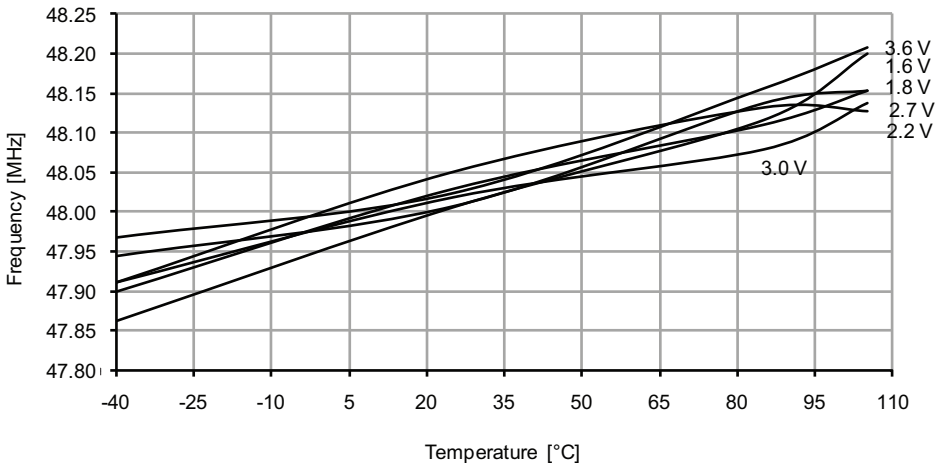


Figure 37-128. Offset error vs. V_{REF}.

T = 25°C, V_{CC} = 3.6V, ADC sampling speed = 500ksps.

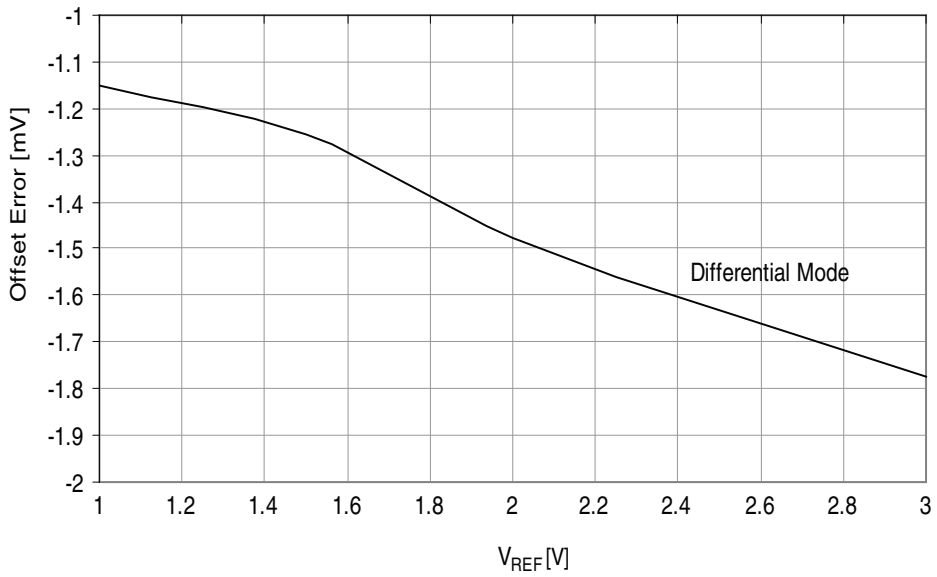
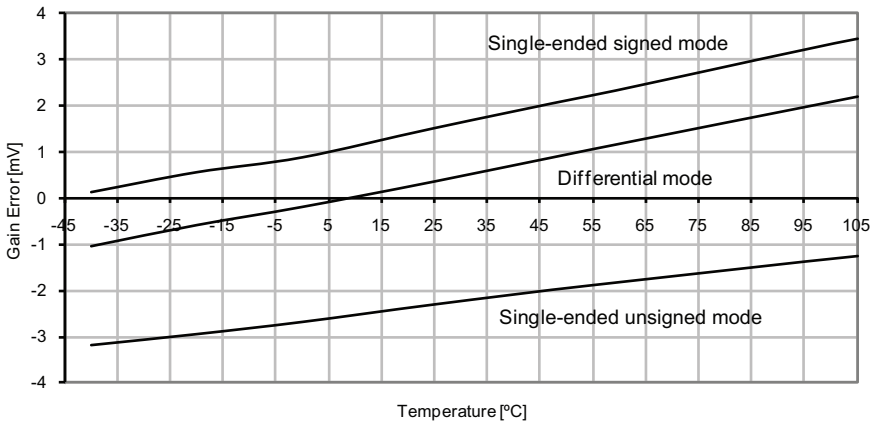


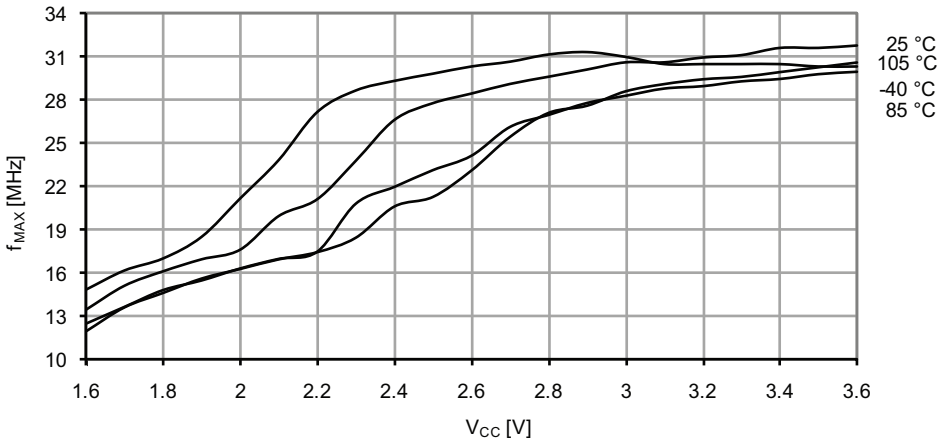
Figure 37-129. Gain error vs. temperature.

V_{CC} = 3.0V, V_{REF} = external 2.0V.



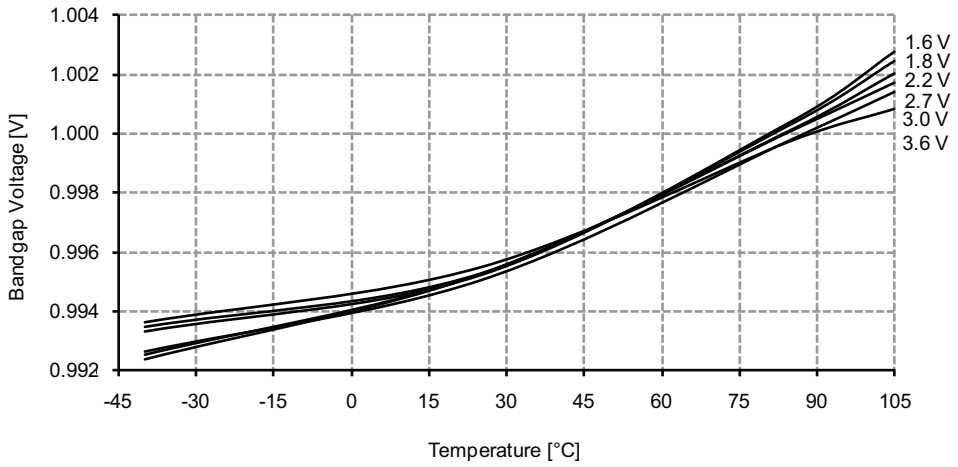
37.2.12 PDI characteristics

Figure 37-168. Maximum PDI frequency vs. V_{CC}.



37.3.6 Internal 1.0V reference Characteristics

Figure 37-227. ADC/DAC Internal 1.0V reference vs. temperature.



37.3.7 BOD Characteristics

Figure 37-228. BOD thresholds vs. temperature.

BOD level = 1.6V.

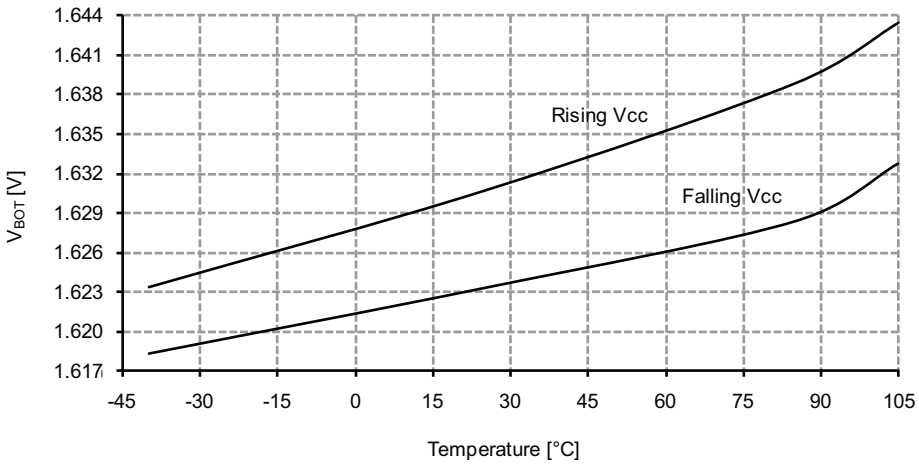


Figure 37-233. Reset pin pull-up resistor current vs. reset pin voltage.

V_{CC} = 3.3V.

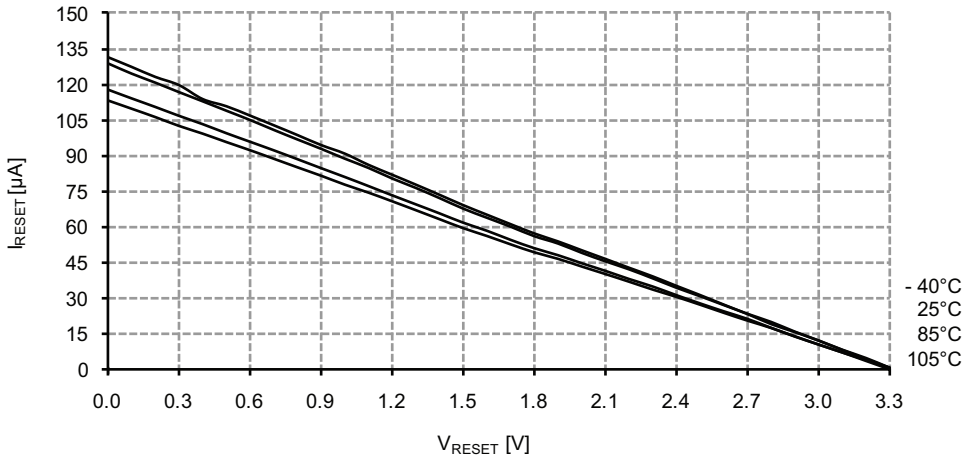


Figure 37-234. Reset pin input threshold voltage vs. V_{CC}.

V_{IH} - Reset pin read as "1".